

# PJQ4411P

## 20V P-Channel Enhancement Mode MOSFET

**Voltage**

**-20 V**

**Current**

**-60 A**

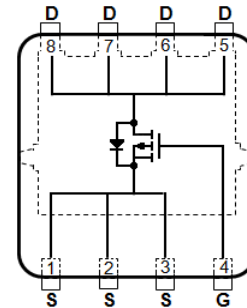
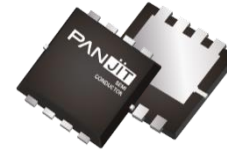
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V, I_D@-8A < 8m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-2.5V, I_D@-5A < 11m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-1.8V, I_D@-3A < 16m\Omega$
- Advanced Trench Process Technology.
- High density cell design for ultra-low on-resistance.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-20	V
Gate-Source Voltage		$V_{GS}$	$\pm 12$	
Continuous Drain Current	$T_C=25^\circ\text{C}$	$I_D$	-60	A
	$T_C=100^\circ\text{C}$		-38	
Pulsed Drain Current <sup>(Note 1,4)</sup>		$I_{DM}$	-200	
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	60	W
	$T_C=100^\circ\text{C}$		24	
Continuous Drain Current	$T_A=25^\circ\text{C}$	$I_D$	-13	A
	$T_A=70^\circ\text{C}$		-10	
Power Dissipation		$P_D$	2.0	W
Power Dissipation			1.3	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{\theta JC}$	2.1	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature

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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.3	-0.6	-1.0	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-8A	-	6	8	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-5A	-	8	11	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-3A	-	11	16	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 6)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	46.8	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	7.4	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	11.1	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	4659	-	pF
Output Capacitance	C <sub>oss</sub>		-	539	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	440	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =25Ω (Note 1,2)	-	42	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	78	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	510	-	
Turn-Off Fall Time	t <sub>f</sub>		-	265	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	-60	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.7	-1	V

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> = 25°C.
4. The maximum current rating is package limited.
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.

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## TYPICAL CHARACTERISTIC CURVES

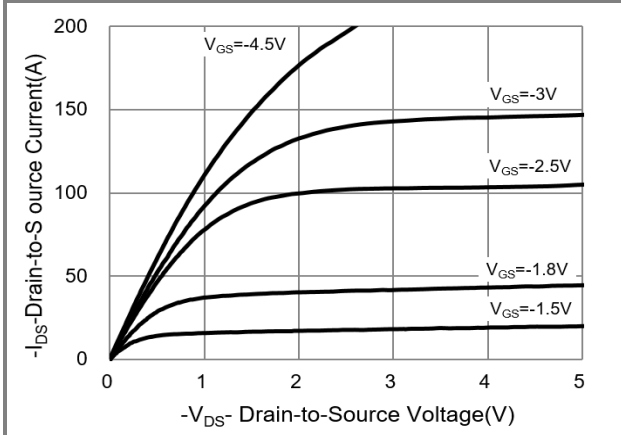


Fig.1 On-Region Characteristics

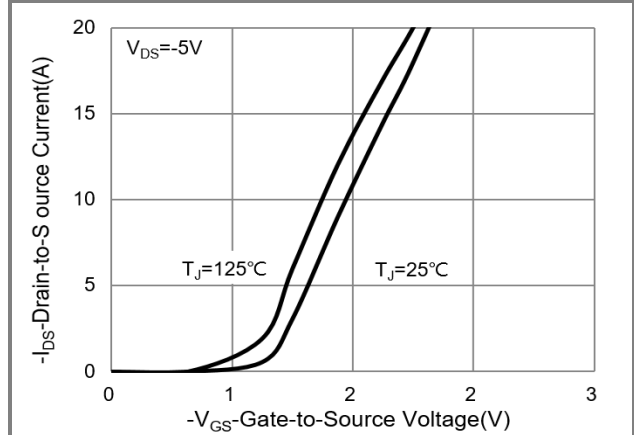


Fig.2 Transfer Characteristics

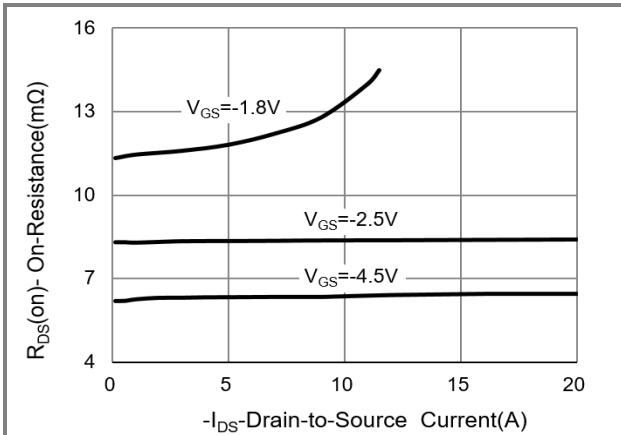


Fig.3 On-Resistance vs. Drain Current

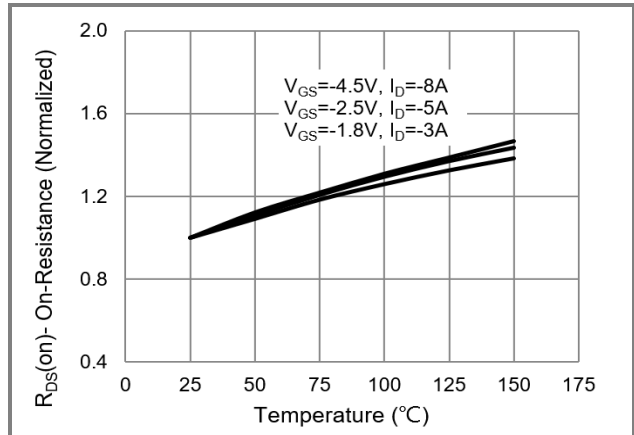


Fig.4 On-Resistance vs. Junction temperature

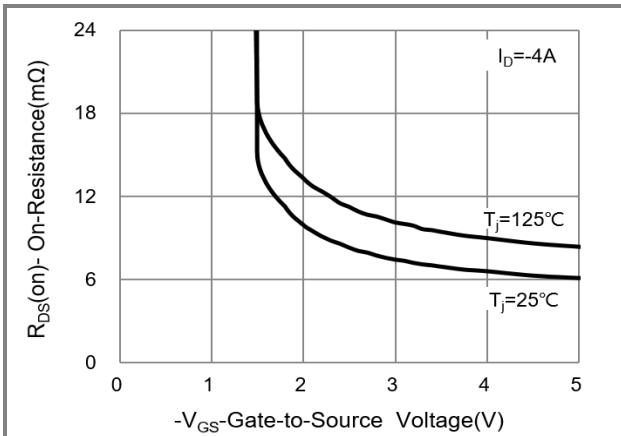


Fig.5 On-Resistance Variation with VGS.

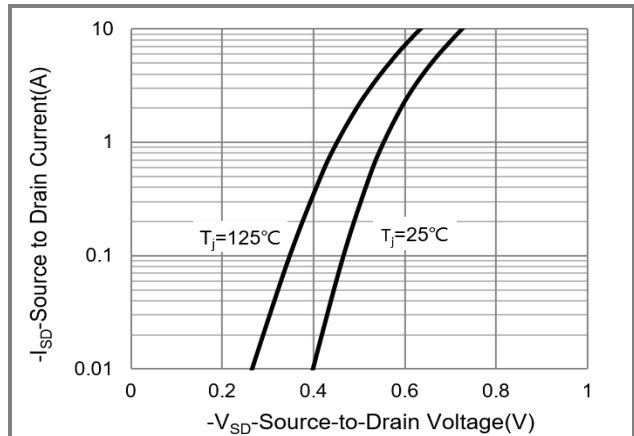


Fig.6 Source-Drain Diode Forward Voltage

# PJQ4411P

## TYPICAL CHARACTERISTIC CURVES

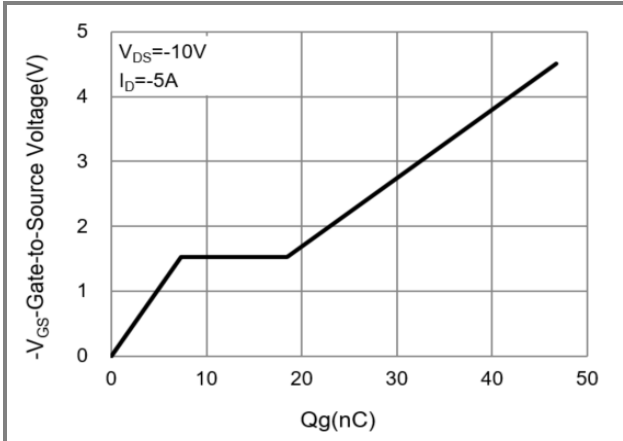


Fig.7 Gate-Charge Characteristics

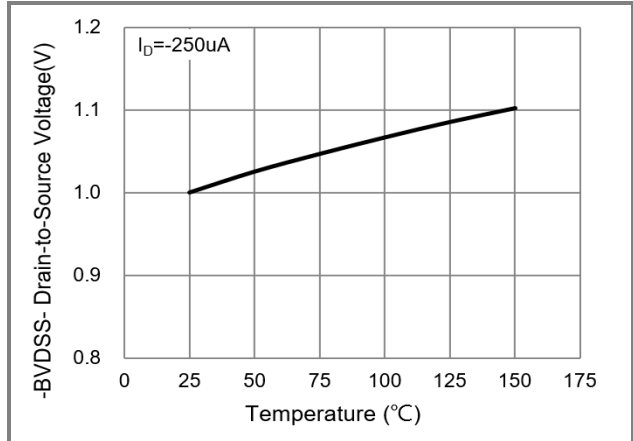


Fig.8 Breakdown Voltage Variation vs. Temperature.

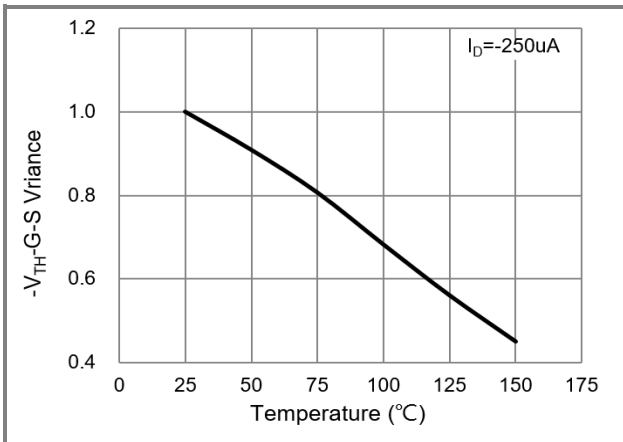


Fig.9 Threshold Voltage Variation with Temperature

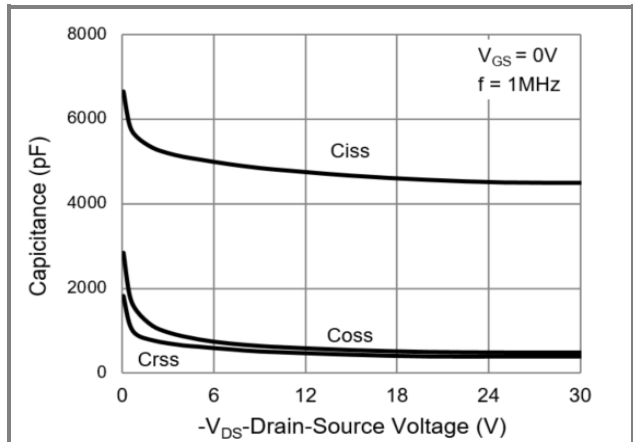


Fig.10 Capacitance vs. Drain-Source Voltage

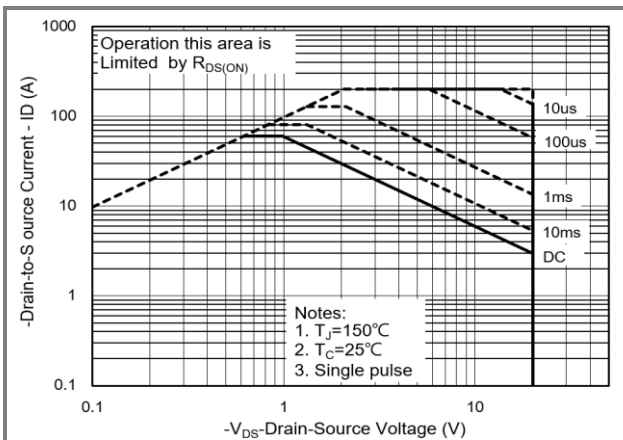


Fig.11 Maximum Safe Operating Area

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## TYPICAL CHARACTERISTIC CURVES

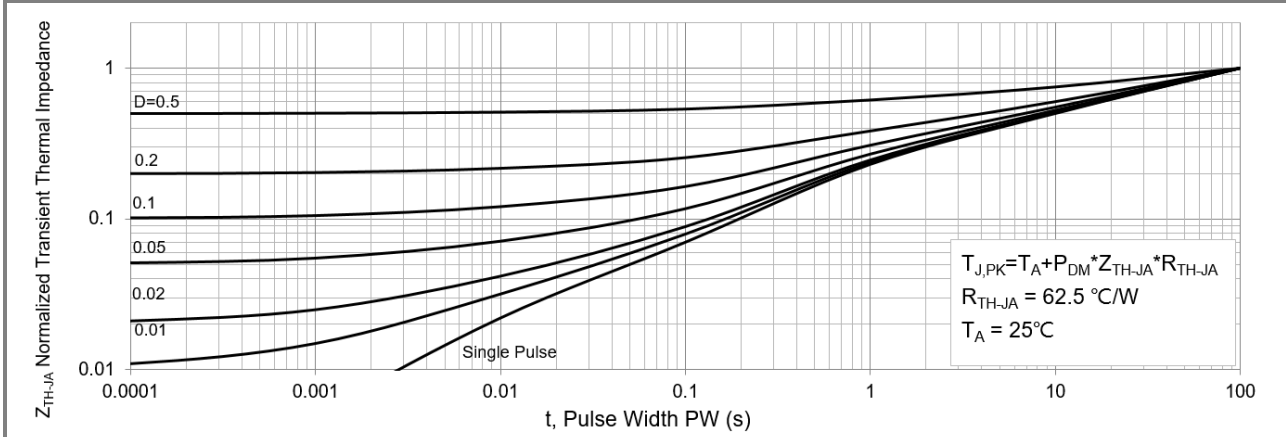


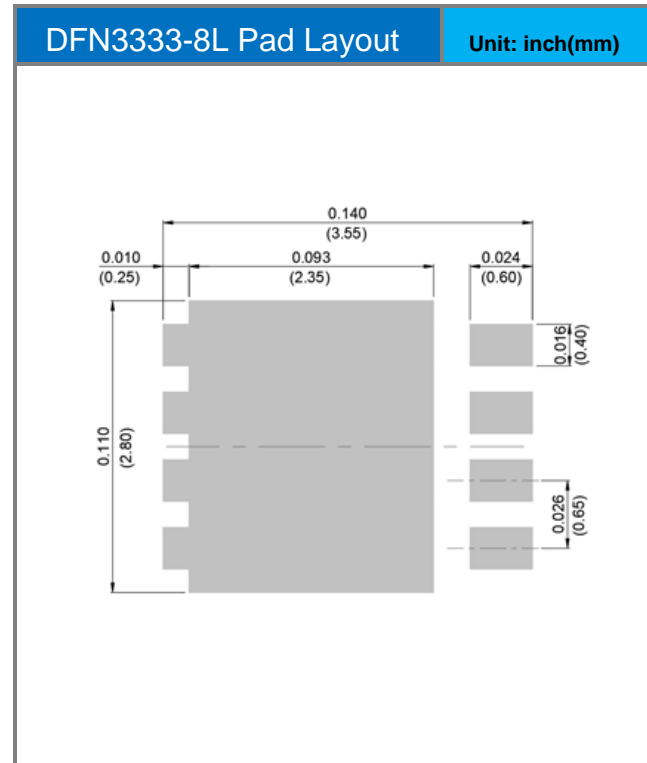
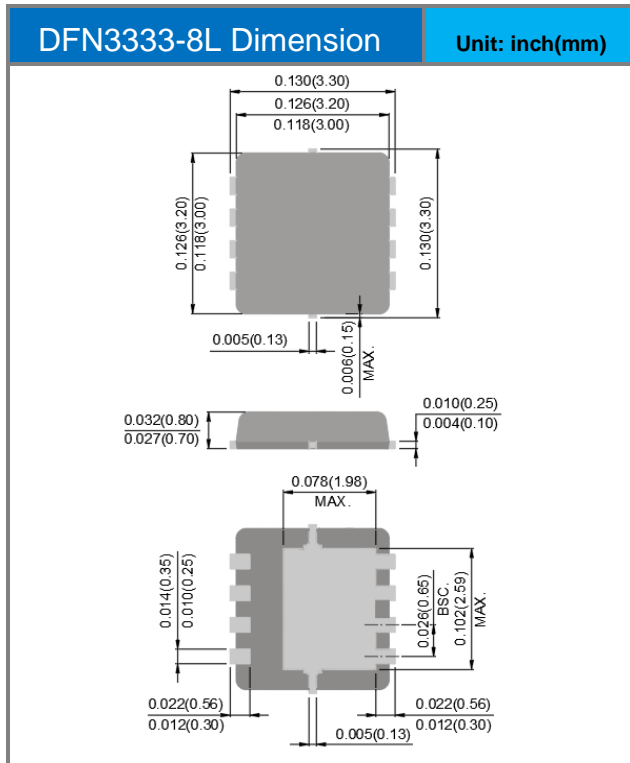
Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

# PJQ4411P

**Part No. Packing Code Version**

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4411P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4411	Halogen free RoHS compliant

## Packaging Information & Mounting Pad Layout



## PJQ4411P

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